

# REPORT DOCUMENTATION PAGE

Form Approved  
OMB No. 0704-0188

Public reporting burden for this collection of information is estimated to average 1 hour per response, including the time for reviewing instructions, searching existing data sources, gathering and maintaining the data needed, and completing and reviewing the collection of information. Send comments regarding this burden estimate or any other aspect of this collection of information, including suggestions for reducing this burden, to Washington Headquarters Services, Directorate for Information Operations and Reports, 1215 Jefferson Davis Highway, Suite 1204, Arlington, VA 22202-4302, and to the Office of Management and Budget, Paperwork Reduction Project (0704-0188), Washington, DC 20503.

1. AGENCY USE ONLY (Leave blank)      2. REPORT DATE      3. REPORT TYPE AND DATES COVERED  
 FINAL REPORT 15 Jan 93 - 14 Jan 96

4. TITLE AND SUBTITLE  
 Physical Properties of Nanometer-Scale Magnets

5. FUNDING NUMBERS  
 61102F  
 2305/GS

6. AUTHOR(S)  
 Professor David D. Awschalom

AFOSR-TR-96  
 0215

7. PERFORMING ORGANIZATION NAME(S) AND ADDRESS(ES)  
 Department of Physics  
 University of California, Santa Barbara  
 Santa Barbara, CA 93106-9530

9. SPONSORING/MONITORING AGENCY NAME(S) AND ADDRESS(ES)  
 AFOSR/NE  
 110 Duncan Avenue Suite B115  
 Bolling AFB DC 20332-0001

10. SPONSORING/MONITORING AGENCY REPORT NUMBER  
 F49620-93-1-0117

11. SUPPLEMENTARY NOTES

12a. DISTRIBUTION / AVAILABILITY STATEMENT  
 APPROVED FOR PUBLIC RELEASE: DISTRIBUTION UNLIMITED

12b. DISTRIBUTION CODE

13. ABSTRACT (Maximum 200 words)

As described in our original proposal, we have spent the final year of our research program investigating the physical properties of nanometer-scale magnets. This has involved several projects and associated experimental techniques.

19960520 039

14. SUBJECT TERMS			15. NUMBER OF PAGES
			16. PRICE CODE
17. SECURITY CLASSIFICATION OF REPORT UNCLASSIFIED	18. SECURITY CLASSIFICATION OF THIS PAGE UNCLASSIFIED	19. SECURITY CLASSIFICATION OF ABSTRACT UNCLASSIFIED	20. LIMITATION OF ABSTRACT

UNIVERSITY OF CALIFORNIA, SANTA BARBARA

DEPARTMENT OF PHYSICS

SANTA BARBARA, CALIFORNIA 93106-9530

Professor David D. Awschalom  
office phone: (805)893-2121  
FAX number: (805)893-4170  
e-mail: AWSCH@LOTEMP.PHYSICS.UCSB.EDU

May 6, 1996

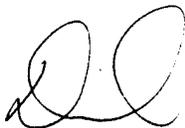
Dr. Harold Weinstock  
Air Force Office of Scientific Research  
Physics and Electronics  
110 Duncan Avenue, Suite B115  
Bolling Air Force Base, DC  
20332-0001

Dear Harold,

The following pages contain the final technical progress report for our Grant #F49620-93-1-0117, "Physical Properties of Nanometer-Scale Magnets", as required by the Air Force Office of Scientific Research.

Please contact me if you require additional information.

Sincerely,



David D. Awschalom  
Professor of Physics

*Final*  
AFOSR Technical ~~Progress~~ Report  
Grant #F49620-93-1-0117  
Final Technical Report

*"Physical Properties of Nanometer-Scale Magnets"*

Professor David D. Awschalom  
Department of Physics  
University of California  
Santa Barbara, CA 93106

### **1. Research Review during the final grant period**

As described in our original proposal, we have spent the final year of our research program investigating the physical properties of nanometer-scale magnets. This has involved several projects and associated experimental techniques, each of which is described in turn below.

#### **Imaging and Magnetometry of Mesoscopic Magnets**

Arrays of nanometer-scale iron particles are grown by local organometallic deposition with a scanning tunneling microscope. The average magnetic properties are studied at low temperatures (5 – 100 K) with a two-dimensional hole gas Hall magnetometer. Rotation of the net array magnetization occurs by both reversible and irreversible modes, the latter revealed by Barkhausen jumps. Direct spatially-resolved measurements at room temperature with a magnetic force microscope show that the discrete jumps are due to the sudden switching of individual single-domain particles. Particles that appear structurally similar are found to be magnetically distinct.

The present work employs the additive technique of local organometallic deposition with a scanning tunneling microscope (STM) to produce nanometer-scale iron particles with control of the shape and orientation. The average magnetic properties of an array of particles is compared with the properties of individual particles by complementary low temperature Hall magnetometer and room temperature magnetic force microscope (MFM) measurements, the latter producing some of the highest resolution magnetic images of submicron structures to date. Although the particles formed with the STM are seen to be structurally similar through atomic-scale topographic studies, they vary magnetically in terms of coercive fields, suggesting that anisotropy on a length scale smaller than the spatial resolution of our probes (~25 nm) is playing an important role.

The Hall magnetometer provides a measure of the *average* magnetic properties of nanometer-scale particles, but requires care in interpretation since particles are not weighted equally. Imaging of individual particles with an MFM explores the current limits of scanning probe microscopy. Although the STM forms particles that are ostensibly similar in structure, magnetically there is found to be a distribution of coercive fields through direct imaging. Magnetic properties may ultimately serve as a more sensitive characterization of nanometer-scale particles, as demonstrated also by the identification of a magnetic film formed concomitant with the growth of the STM particles. However, the effect of the MFM tip on small particles can be significant. One of the outstanding challenges is the development of magnetic probes which are less invasive.

## Femtosecond Near-field Spin Microscopy in Digital Magnetic Heterostructures

A detailed understanding of spin scattering in mesoscopic electronic systems remains, for the most part, an open issue in condensed matter physics. To directly investigate the dynamic behavior of electronic spin, one needs to develop both a host material in which the fundamental spin interactions are well understood, and techniques for probing spin scattering on the relevant time and length scales. Extensive research in recent years has identified II-VI magnetic semiconductor quantum structures as flexible systems in which to study electronic spin interactions in a well-characterized environment. In such systems, the strong exchange coupling between electronic states and paramagnetically aligned magnetic ions results in large effective Landé  $g$ -factors at low temperatures ( $g_{\text{eff}} \sim 400$  at  $T=4$  K). Quantum well (QW) confinement enhances by several orders of magnitude the coupling of excitonic states to visible light, enabling a wide array of optical techniques to be used. The Zeeman splittings in recently grown structures can be made much larger than inhomogeneous linewidths, providing model field-tunable two-level systems ideal for magneto-optical studies of spin-dependent phenomena.

Conventional time-resolved optical spectroscopies have successfully probed dynamical spin-dependent phenomena in this class of structures, yielding important information about exciton spin scattering and magnetic relaxation. However, to examine directly the role of interfaces, alloy fluctuations, disorder, local magnetic environments, impurities and defects on excitonic spin *transport* -- factors which involve *spatial degrees of freedom* -- one requires a technique capable of resolving the relevant physical lengthscales, from exciton diffusion lengths ( $\sim 1 \mu\text{m}$ ) to magnetic correlation lengths ( $> 50$  nm in antiferromagnetically ordered MnSe), to the exciton Bohr radius ( $\sim 4$  nm for ZnSe/ZnCdSe). Conventional optical techniques, being diffraction limited, cannot provide sufficient resolution on the lengthscales of interest. Near-field scanning optical microscopy (NSOM) circumvents the diffraction limit and, combined with femtosecond-resolved spectroscopies, provides a unique capability of interrogating spatio-temporal excitonic spin dynamics in magnetic semiconductors.

Static and time-resolved luminescence studies of excitonic spin behavior in magnetic semiconductor QWs have been performed using a low-temperature polarization-resolved NSOM. A series of patterned defects, introduced by  $\text{Ga}^+$  focused-ion-beam implantation, reduces both the QW luminescence intensity and the local  $g$ -factor, creating a magnetic-field-driven, spin-dependent energy landscape for diffusing excitons. Carrier spin distributions are inferred from the near-field images of the DC luminescence intensity and polarization. Exciton diffusion is found to have a minimal effect on the local magnetic interactions which contribute to Zeeman split states. The incorporation of time resolution, using a luminescence intensity correlation technique, provides additional evidence for spin-dependent exciton diffusion. Time-resolved absorption, another powerful tool, provides direct information about the spatiotemporal evolution of photoexcited excitons. Fundamental limitations on the measurement of polarized luminescence from semiconductors in the near field are demonstrated and discussed.

## Submicron Ferromagnets in Mn-implanted III-V Semiconductors

Microscopic ferromagnets can be fabricated *on* semiconductor substrates in a number of ways, including electron-beam lithographic patterning, scanning tunneling microscope deposition, and electrochemical etching and electrodeposition. In order to enhance the effective interaction between electronic carriers and local ferromagnetic

fields, it is desirable to locate ferromagnetic clusters *within* a semiconductor. This is a challenge since the solubility of magnetic ions in semiconductors is generally low. Because Mn ions replace Ga in the GaAs lattice and act as acceptors, it is possible to incorporate localized ferromagnetic structures inside the GaAs semiconductor while preserving its electronic and optical properties. This may be achieved by ion implantation and subsequent heat treatment. Although the solubility of Mn ions in GaAs is very low under equilibrium conditions, a relatively high concentration ( $\sim 10^{21} \text{ cm}^{-3}$ ) can be obtained by implanting the ions into the semiconductor. During rapid thermal annealing at  $T > 600 \text{ C}$ , the uniformly implanted Mn ions diffuse and combine with Ga to form submicron GaMn microcrystallites (150 - 400 nm) which are ferromagnetic at room temperature. A structure containing an ensemble of particles has a magnetization that can be reversed at the coercive field  $H_C \sim 6 \text{ kOe}$ , and becomes paramagnetic above the Curie temperature  $T_C > 400 \text{ K}$ . These particles are larger than the typical magnetic particles (1 - 10 nm) in granular GMR materials and in fact, large enough that the magnetic moments may not be uniform throughout the particle, *i.e.*, the particle consists of magnetic domains. In this instance, the GaAs host plays an important role in determining the magnetic properties such as the domain orientation.

The GaMn ferromagnets are formed near the GaAs surface and may be directly probed by atomic (AFM) and magnetic force microscopy (MFM) at room temperature. In MFM images, the contrast is caused by spatial variations in the magnetic interaction between the magnetized probe and the stray magnetic fields of the sample. While the ferromagnetic particles ( $\sim 400 \text{ nm}$ ) produce strong magnetic force contrast, there exist particles ( $\sim 50\%$ ) which show only weak contrast. The latter particles are likely ferromagnets with very low coercive fields and moment densities or possibly even superparamagnets at room temperature.

One can infer the magnetic state of the GaMn precipitates from these MFM images. To a good approximation, the MFM probe behaves like a localized magnetic dipole, and the imaging of spherical single-domain particles can be modeled by a dipole-dipole interaction. We have calculated single particle images based on this approximation for several different configurations. A more detailed model which integrates dipole moments over the surface of the tip produces similar node structures. These simulations show that one can obtain a variety of patterns from a single-domain particle, depending on the relative orientation between the tip and particle moments. However, with a perpendicularly magnetized tip, such as is used to produce the data in, the simulations of single-domain particles do not show the complicated four-component contrast observed. Thus, these two precipitates must be multi-domain magnetic particles, while the others are single-domain particles. Such simulations demonstrate the importance of understanding the interplay between instrumental sensor and sample cluster magnetic fields for meaningful particle imaging in mesoscopic dimensions.

In an unmagnetized sample, particles within this length scale can be single-domain or multi-domain. In a field, multi-domain GaMn particles are converted to single-domain particles; in particular, the single-domain moments are observed to preferentially align along the three equivalent crystalline axes ( $\langle 100 \rangle$ ,  $\langle 010 \rangle$ ,  $\langle 001 \rangle$ ) of the GaAs host after the field is removed. The behavior of ferromagnetic particles can also be studied by continuously applying an in-plane field. For fields stronger than the tip coercive field ( $\sim 400 \text{ Oe}$ ), the tip is forced to align with the in-plane field, thus allowing simple image interpretation. As the in-plane field is increased, the moments tend to align with the field direction, displaying two types of motion: discontinuous reversal and gradual rotation of the magnetization, depending on the relative orientation between the magnetic easy axis and the applied field.

These processes can be investigated directly by imaging single particles in real time while ramping the in-plane applied field. A large variation (about a factor of three) in the switching field is also found among particles with approximately the same easy

axis orientation. As these particles are likely to have the same crystalline structure with similar strain, this variation may be due to shape anisotropy. Further investigations should reveal the magnetic anisotropy and micromagnetic behavior of these single-domain magnets as well as their role in modifying electronic transport.

### Mechanical Detection of Magnetism: Microfabricated Cantilevers

The fabrication of very delicate mechanical cantilevers combined with sensitive displacement detection schemes has resulted in a number of remarkably powerful experimental techniques, including scanning force microscopies, mechanically detected magnetic resonance, and a new class of torque magnetometers. In general, the force sensitivity of these techniques can be improved by lowering the spring constant  $k$  of the cantilever (thereby increasing the displacement per unit force) and increasing the resonant frequency  $\omega_0$  (decreasing the necessary averaging time). Since most semiconductors and metals have mass densities and elastic moduli within an order of magnitude of each other, the design parameters that afford the greatest opportunities for improvements are the physical dimensions of the cantilever. Specifically, for a rectangular cantilever, one can achieve small  $k$  and large  $\omega_0$  by simultaneously decreasing all the dimensions.

Typically, micron-scale cantilevers are fabricated from silicon, silicon oxide, or silicon nitride. Fabricating cantilevers from the GaAs/Al<sub>x</sub>Ga(1-x)As materials presents challenges in designing new processes for the III-V chemistry. More importantly, it offers the advantages of integration with optical devices, magnetic systems, and strain sensing elements that utilize the piezoelectric properties of the GaAs to detect the cantilever displacement. Cantilevers fabricated from the III-V semiconductors have usually contained Al-rich layers (included as part of a laser structure), which simplify the fabrication of free mechanical structures by allowing the selective etching of the GaAs substrate out from under the Al-rich layers. During this period we have successfully designed a process for making cantilevers from a single epilayer of GaAs grown by molecular beam epitaxy (MBE) on an AlAs etch stop layer on a [100] GaAs single crystal substrate. We have fabricated cantilevers 100 nm thick, comparable to the thinnest cantilevers fabricated from silicon and much thinner than cantilevers previously fabricated from GaAs/AlGaAs. This process allows easy access to both sides of the cantilever by etching a window through the entire thickness of the GaAs substrate, unlike previous GaAs/AlGaAs cantilever processes. We have characterized the resonant frequency, quality factor ( $Q$ ) and spring constant of a 100 nm thick GaAs cantilever fabricated in this fashion.

To construct very thin cantilevers made of a single material (as opposed to GaAs/AlGaAs layers), we use MBE to grow a 100 nm thick GaAs epilayer on a 300 nm thick AlAs epilayer on a [100] GaAs substrate. The GaAs epilayer will ultimately form the cantilever, and so its thickness determines that of the cantilever; the AlAs serves as an etch stop and a sacrificial layer. The lateral shape of the cantilever is defined by optical lithography in photoresist spun on the epilayers. In the present case, the pattern is of the form of a window with a cantilever extending into the window. This pattern provides protection to the cantilever against damage in later fabrication steps as well as in actual use. This pattern is then etched into the epilayers by a Cl<sub>2</sub> reactive ion etch.

The cantilevers were mounted on a piezoelectric crystal and driven over a range of frequencies in order to measure  $\omega_0$ ,  $k$ , and  $Q$ . Here we take  $Q = (\Delta\omega / \omega_0)$ , where  $\Delta\omega$  is the FWHM of the cantilever response. Their displacement was measured using laser interferometry. The response of a 135 mm long, 30 mm wide and 100 nm thick cantilever as a function of the driving frequency at room temperature and pressure shows a resonant frequency of 4.5 kHz and a  $Q$  of  $\sim 2$ . Note that this value is expected to increase by several orders of magnitude in vacuum, as the lever is heavily damped under atmospheric

conditions. In addition, we have measured the absolute magnitude of the Fourier transform of the (undriven) noise in the interferometer. The technique of measuring the thermal noise of the cantilever has many advantages over the driving approach, in particular the fact that the spectral weight of the thermal noise tends to select the "soft" (small  $k$ ) modes and reject the large  $k$  modes, which include the modes of the mounting itself, whereas the response of a mode to the piezo driving force is insensitive to the mode's  $k$ . The thermal noise gives values of  $n_0$  and  $Q$  that are consistent with the piezo-driven measurement. Because of the cantilevers' large aspect ratio and low mass, air damping limits the  $Q$ . The thermal noise of the same cantilever at a pressure of 250 mTorr shows that  $n_0$  has increased to 5.1 kHz and  $Q$  to  $\sim 9$ . From this value of the resonance frequency, we find  $k \sim 10^{-4}$  N/m. This spring constant is smaller than for any other cantilever of which we are aware. Given a DC displacement sensitivity of 1 nm, this results in a DC force sensitivity of  $\sim 10^{-13}$  N.

We intend on exploiting the sensitivity of these microfabricated detectors to explore the classical and low temperature quantum spin dynamics in mesoscopic quantum magnetic spin systems grown through chemical techniques. In particular, new single crystals of iron-based molecular magnets have been grown in a collaboration between the physics and chemistry departments at UC-Santa Barbara. Crystals of molecules containing 8, 10, or 12 iron atoms have been grown by crystallization from solution and characterized by x-ray diffraction and angle-resolved SQUID magnetometry. The iron atoms within these molecules are arranged in different configurations and are magnetically coupled to each other by superexchange through organic ligands. Depending on the geometry of the molecule, the coupling between spins can give rise to a variety of different ground states. For  $T > 1.7$  K, there are no inter-molecular interactions in the crystalline state, and the crystal assembly is an ensemble of identical finite spin systems with calculable, discrete spectra. We will explore the dynamics of the molecular magnetization in pulsed magnetic fields, measure the field-driven spin splitting, and determine the potential for field-tuning coherent tunneling phenomena between energy-degenerate eigenstates.

## 2. Publications during the final grant period

### *Peer-reviewed journal articles*

1. S. A. Crooker, D. D. Awschalom, N. Samarth, "Time-resolved Faraday Spectroscopy of Spin Dynamics in Digital Magnetic Heterostructures," Invited Article for the Special Issue of Applied Optical Diagnostics of Semiconductors, *IEEE Journal of Selected Topics in Quantum Electronics* **1**, 1082 (1995).
2. J. Shi, J. M. Kikkawa, R. Proksch, T. Schaeffer, D. D. Awschalom, G. Medeiros-Ribeiro, P. M. Petroff, "Assembly of Submicron Ferromagnets in GaAs Semiconductors," *Nature*, **377**, 707 (1995).
3. D. A. Tulchinsky, S. A. Crooker, J. Levy, V. Nikitin, N. Samarth, D. D. Awschalom, "New Dynamical Spectroscopies in Digital Magnetic Heterostructures," *Proceedings of the Conference on Physical Phenomena in High Magnetic Fields*, ed. by Lev Gorkov [World Scientific, London, 1996].
4. J. Levy, V. Nikitin, J. M. Kikkawa, A. Cohen, D. D. Awschalom, N. Samarth, R. Garcia, "Spatiotemporal Near-Field Spin Microscopy in Patterned Magnetic Heterostructures," *Physical Review Letters* **76**, 1948 (1996).

5. S. Gider, D.D. Awschalom, T. Douglas, K. Wong, S. Mann, G. Cain, "Classical and Quantum Magnetism in Synthetic Ferritin Proteins," *J. Appl. Phys.* **79**, X (1996).
6. J. Shi, J. Kikkawa, D.D. Awschalom, G. Medeiros-Ribeiro, P. M. Petroff, K. Babcock, "Magnetic Properties and Imaging of Mn-Implanted GaAs Semiconductors," **79**, X (1996).
7. J. Levy, V. Nikitin, D.D. Awschalom, "Femtosecond Near-field Spin Microscopy in Digital Magnetic Heterostructures," Invited Article for the *Journal of Applied Physics*, *J. Appl. Phys.* **79**, X (1996).
8. J. Shi, S. Gider, K. Babcock, and D. D. Awschalom, "Magnetic Clusters in Semiconductors, Metals, and Molecular Beams," *Science* **271**, 937-941 (1996).
9. S. Gider, J. Shi, P. F. Hopkins, K. L. Campman, A. C. Gossard, D. D. Awschalom, A. D. Kent, and S. von Molnar, "Imaging and Magnetometry of Switching in Nanometer-Scale Iron Particles," *Physical Review B*, Rapid Communications, submitted for publication (1996).
10. K. L. Babcock, V. E. Elings, J. Shi, D. D. Awschalom, and M. Dugas, "Field-Dependence of Microscopic Probes in Magnetic Force Microscopy," *Applied Physics Letters*, accepted for publication (1996).
11. S. Gider, D. D. Awschalom, D. P. DiVincenzo, and D. Loss, "Does Macroscopic Quantum Coherence Occur in Ferritin?," *Science* **272**, 424 (1996).
12. L. Cristofolini, K. Prassides, K. Vavakis, A. Amato, F. Gygax, A. Schenck, S. Gider, and D. D. Awschalom, "A  $\mu^+$ SR Study of the Magnetic Properties of Ferritin," *Hyper. Int.*, accepted for publication (1996).
13. J. G. E. Harris, D. D. Awschalom, K. D. Maronowski, and A. C. Gossard, "Fabrication and Characterization of 100 nm Thick GaAs Cantilevers," accepted for publication, *Rev. Sci. Inst.* (1996).

### **3. Invited Talks during this grant period and accepted invitations**

1. D. D. Awschalom, "Nanomagnetism," NATO Forum on Nanoscale Science and Technology, Toledo, Spain, May 11-16, 1997.
2. D. D. Awschalom, "Spin Dynamics in Magnetic/Semiconductor Quantum Structures," Lecture Course at the 14th NATO Advanced Study Institute on the Dynamical Properties of Unconventional Magnetic Systems," Geilo, Norway, April 2-12, 1997.
3. D. D. Awschalom, "Spatiotemporal Near-field Spin Microscopy in Digital Magnetic Heterostructures, Symposium on Near-field Optical Microscopy and Spectroscopy, LEOS Annual Meeting, Boston, MA, November 18-21, 1996.
4. D. D. Awschalom, "Classical and Quantum Properties of Mesoscopic Magnets," Fifth International Conference on the Physics of Transition Metals, Osaka, Japan, September 24-27, 1996.

5. D. D. Awschalom, "Classical and Quantum Dynamics of Nanometer-Scale Magnets," Fourth International Conference on Nanometer-Scale Science and Technology, Beijing, China, September 8-12, 1996.
6. D. D. Awschalom, "Classical and Quantum Behavior of Nanometer-scale Magnets," Symposium on Macromaterials, Annual Meeting of the American Chemical Society, Orlando, FL, August 25-29, 1996.
7. D. D. Awschalom, "Spatiotemporal Spin Dynamics in Magnetic Quantum Structures," Seminar of the Munich Physicists, Ludwig-Maximilians-University, Munich, Germany, July 29, 1996.
8. D. D. Awschalom, "Spatiotemporal Near-Field Spin Spectroscopy in Digital Magnetic Heterostructures," 23rd International Conference on the Physics of Semiconductors, Berlin, Germany, July 21-26, 1996.
9. N. Samarth and D. D. Awschalom, "Spin Coherence and Imaging in Magnetic Quantum Systems," International Conference on Quantum Devices and Circuits, Alexandria, Egypt, June 4-8, 1996.
10. D. D. Awschalom, "Spatiotemporal Near-Field Spin Microscopy in Patterned Magnetic Heterostructures," Quantum Electronics and Laser Science Conference, Anaheim, CA, June 2-7, 1996.
11. D. D. Awschalom, "Complex Dynamics of Nanometer-Scale Magnets," Ohio Section Spring Meeting of the American Physical Society, Columbus, OH, April 12-13, 1996.
12. J. Shi (and D. D. Awschalom), "Assembly of Submicron Ferromagnets in GaAs Semiconductors," Meeting of the American Physical Society, St. Louis, MO, March 18-22, 1996.
13. D. D. Awschalom, "Complex Dynamics of Mesoscopic Magnets," Physics Colloquium, Yale University, New Haven, CT, March 1, 1996. (Declined)
14. D. D. Awschalom, "Complex Dynamics of Mesoscopic Magnets," Physical Colloquium, SUNY-Stonybrook, Stonybrook, NY, February 6, 1996.
15. D. D. Awschalom, "Spatiotemporal Near-Field Spin Microscopy in Digital Magnetic Heterostructures," Condensed Matter Physics Seminar, Harvard University, Boston, MA, February 2, 1996.
16. D. D. Awschalom, "Complex Dynamics of Mesoscopic Magnets," Physics Colloquium, University of California, Riverside, CA, January 11, 1996.
17. D. D. Awschalom, "Femtosecond Near-Field Spin Microscopy in Digital Magnetic Heterostructures," 40th Annual Conference on Magnetism and Magnetic Materials, Philadelphia, PA, November 6-9, 1995.
18. D. D. Awschalom, "Spatiotemporal Near-Field Spin Microscopy in Patterned Magnetic Heterostructures," Frontiers in Electronic Low-Dimensional Systems, Weizmann Institute of Science, Israel, October 29, 1995.

#### **4. Contributed Talks during the grant period and forthcoming**

1. V. Nikitin, P. A. Crowell, J. Levy, F. Flack, N. Samarth, and D. D. Awschalom, "Near-field Optical Spectroscopy of Magnetic Semiconductor Quantum Dots," 23rd International Conference on the Physics of Semiconductors, Berlin, Germany, July 21-26, 1996.
2. K. Babcock, V. Elings, J. Shi, D. D. Awschalom, M. Dugas, "Measurements of Probe Coercivity for Magnetic Force Microscopy," Intermag-96, Seattle, Washington, April 9-12, 1996.

3. J. G. E. Harris, S. Gider, D. D. Awschalom, W. W. Lukens, G. Stucky, K. D. Marinowski, A. C. Gossard, "Magnetic Properties of Iron-Based Molecular Spin Systems," Meeting of the American Physical Society, St. Louis, MO, March 18-22, 1996.
4. D. K. Young, J. Levy, J. M. Kikkawa, D. D. Awschalom, "Cantilever Model Near-Field Spectroscopy of Patterned GaAs/AlGaAs Heterostructures," Meeting of the American Physical Society, St. Louis, MO, March 18-22, 1996.
5. V. Nikitin, J. Levy, P. A. Crowell, D. D. Awschalom, F. Flack, N. Samarth, "Spatiotemporal Spin Transport in Patterned Magnetic Heterostructures," Meeting of the American Physical Society, St. Louis, MO, March 18-22, 1996.
6. J. Levy, V. Nikitin, P. A. Crowell, D. D. Awschalom, F. Flack, I. Smorchkova, N. Samarth, "Low-Temperature Near-Field Spin Microscopy of Localized Magnetic Semiconductor Quantum States," Meeting of the American Physical Society, St. Louis, MO, March 18-22, 1996.
7. J. M. Kikkawa, J. Shi, P. M. Petroff, D. D. Awschalom, K. Babcock, "Patterning of Submicron Magnets in GaAs by FIB Implantation of Mn," Meeting of the American Physical Society, St. Louis, MO, March 18-22, 1996.
8. S. Gider, D. D. Awschalom, K. L. Campman, A. C. Gossard, J. J. Heremans, S. von Molnar, "Imaging and Magnetometry of STM Fabricated Magnets," Meeting of the American Physical Society, St. Louis, MO, March 18-22, 1996.
9. S. Gider, D.D. Awschalom, "Classical and Quantum Magnetism in Synthetic Ferritin Proteins", 40th National Conference on Magnetism and Magnetic Materials, Philadelphia, PA, November 6-10, 1995.
10. J. Shi, J. Kikkawa, D.D. Awschalom, "Submicron Ferromagnets in Mn-Implanted Semiconductors", 40th National Conference on Magnetism and Magnetic Materials, Philadelphia, PA, November 6-10, 1995.
11. J. M. Kikkawa, J. Shi, and D. D. Awschalom, "Submicron Ferromagnetics in Mn-Implanted Semiconductors," Gordon Research Conference on Magnetic Nanostructures, Irsee, Germany, September 17-22, 1995.